X-1363 US

Title Of Invention:

DECLARATION (37 CFR 1.63) FOR UTILITY OR DESIGN PATENT APPLICATION USING AN **APPLICATION DATA SHEET (37 CFR 1.76)**

Docket No.

SELF-REPAIRING REDUNDANCY FOR MEMORY BLOCKS IN I ROGRAMMABLE LOGIC DEVICES
As a below named inventor(s), I/We declare that:
This declaration is directed to:
The attached application, or Application No
as amended (on) (if applicable);
/We believe I/We am/are the original and first inventor(s) of the subject matter which is claimed and or which a patent is sought;
/We have reviewed and understand the contents of the above-identified application, including the laims, as amended by any amendment specifically referred to above;
/We acknowledge the duty to disclose to the United States Patent and Trademark Office all information mown to me/us to be material to patentability as defined in 37 CFR 1.56, including material information which became available while the application was pending in the United States Patent and Trademark Office; and
All statements made herein of my own knowledge are true, all statements made herein on information and relief are believed to be true, and further that these statements were made with the knowledge that willful alse statements and the like are punishable by fine or imprisonment, or both, under 18 U.S.C. 1001, and may jeopardize the validity of the application or any patent issuing thereon.
FULL NAME OF INVENTOR(S)
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Signature: Date MOV 10 03
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